

Organic electrochemical transistors

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Abstract | Organic electrochemical transistors (OECTs) make effective use of ion injection from an electrolyte to modulate the bulk conductivity of an organic semiconductor channel. The coupling between ionic and electronic charges within the entire volume of the channel endows OECTs with high transconductance compared with that of field-effect transistors, but also limits their response time. The synthetic tunability, facile deposition and biocompatibility of organic materials make OECTs particularly suitable for applications in biological interfacing, printed logic circuitry and neuromorphic devices. In this Review, we discuss the physics and the mechanism of operation of OECTs, focusing on their identifying characteristics. We highlight organic materials that are currently being used in OECTs and survey the history of OECT technology. In addition, form factors, fabrication technologies and applications such as bioelectronics, circuits and memory devices are examined. Finally, we take a critical look at the future of OECT research and development.

The invention of the transistor in 1947 heralded the era of microelectronics. Made of semiconductors, dielectrics and metals, the transistor enabled control of the flow of electrons in a solid-state device, thereby providing a robust alternative to vacuum tubes. Its miniaturization led to the development of the integrated circuit, which is at the heart of every modern electronic device. Modern transistors rely on field-effect doping; the number of mobile electrons (n-type) or holes (p-type) inside a semiconductor is modulated by a voltage applied to a metallic electrode, which is separated from the semiconductor by a thin insulating layer (the gate dielectric)¹. Such devices are referred to as MOSFETs, which is short for metal-oxide-semiconductor field-effect transistors. Interest in organic electronic materials, and in particular their potential for low-cost fabrication over large areas, led to the development of organic field-effect transistors (OFETs)². These devices use conjugated, semiconducting small molecules and polymers and offer an alternative to inorganic devices for applications in which facile processing on different substrates and tunable electronic properties are required. Steady progress over the past three decades has led to the systematic development of materials with mobilities well above those of amorphous silicon, combined with impressive stability^{3,4}. The potential of OFETs has been demonstrated in a variety of applications, including pixel drivers for displays⁵, bionic skin⁶, stretchable transistors⁷ and extremely sensitive chemical sensors⁸ that are even able to withstand operation in saltwater⁹.

The organic electrochemical transistor (OECT) was developed by Wrighton and colleagues¹⁰ in the

mid-1980s. An OECT consists of an organic semiconductor film that is in contact with an electrolyte, in which an electrode (the gate) is immersed (FIG. 1a). Metal electrodes, called the source and drain, establish contact with the organic semiconductor film and define the channel through which holes or electrons flow from the source to the drain. An OECT relies on ions that are injected from the electrolyte into the organic film, thereby changing its doping state and hence its conductivity¹¹. The operation, which is described using the terminology of both electrochemistry and solid-state physics, is controlled by voltages applied to the gate (gate voltage, V_G) and to the drain (drain voltage, V_D), which are referenced with respect to the source electrode. The gate voltage controls the injection of ions into the channel and therefore the doping state (redox state in the language of electrochemistry) of the organic film. The drain voltage induces a current (drain current, I_D), which is proportional to the quantity of mobile holes or electrons in the channel, and therefore probes the doping state of the organic film. Like MOSFETs and OFETs, OECTs operate like a switch, in which the gate voltage (input) controls the drain current (output). They can also be viewed as an amplifier, in which the power of an input signal is amplified on the way to the output¹².

A typical material for OECTs is the conducting polymer poly(3,4-ethylenedioxythiophene) doped with poly(styrene sulfonate) (PEDOT:PSS). The semiconducting PEDOT is p-type doped (oxidized in the language of electrochemistry), which leads to mobile holes that can hop from one chain to another, resulting

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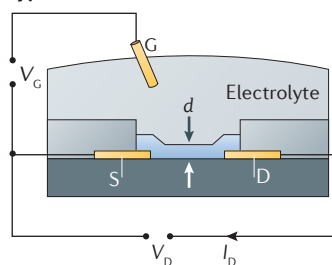
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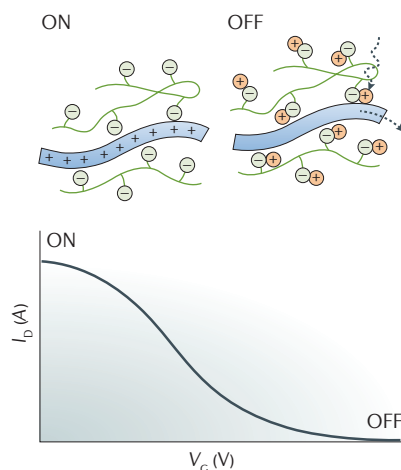
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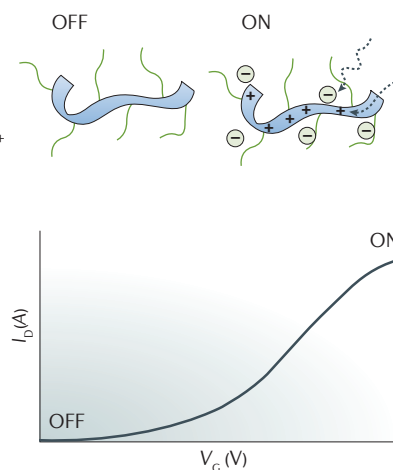
a Typical OECT structure



b Depletion-mode OECT



c Accumulation-mode OECT



d Electronic and ionic circuits

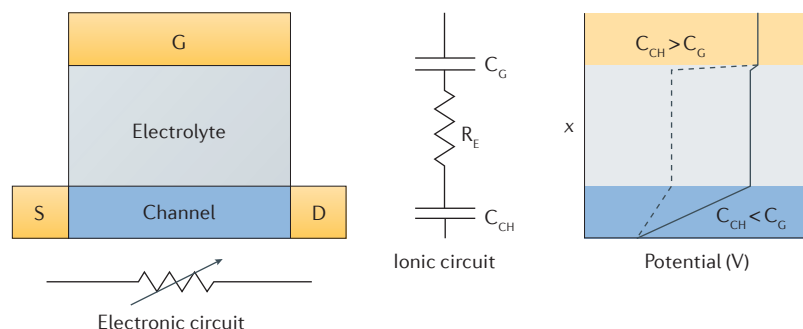


Figure 1 | The device physics of organic electrochemical transistors. **a** | The typical structure of an organic electrochemical transistor (OECT), showing the source (S), drain (D), electrolyte and gate (G). **b** | Transfer curve showing depletion-mode operation of an OECT with a conducting polymer channel. At zero gate voltage, holes on the conducting polymer contribute to a high drain current and the transistor is ON. When a gate voltage is applied, the holes are replaced by cations and the transistor is OFF. **c** | Transfer curve showing accumulation-mode operation of an OECT with a semiconducting polymer channel. At zero gate voltage, the channel has few mobile holes and the transistor is OFF. When a gate voltage is applied, holes accumulate and compensate injected anions, and the transistor is ON. **d** | Ionic and electronic circuits used to model OECTs. The electronic circuit, shown below the device layout on the left, is modelled as a resistor with a resistance that varies upon gating. The ionic circuit, shown in the middle, consists of capacitors corresponding to the channel, C_{CH} , and gate, C_G , respectively, and a resistor corresponding to the electrolyte, R_E . The panel on the right shows the distribution of potential in the ionic circuit. The solid line corresponds to the case of efficient gating, in which most of the applied gate voltage drops at the electrolyte–channel interface, driving ions inside the channel. The dashed line corresponds to the case of poor gating, where most of the applied gate voltage drops at the gate–electrolyte interface. d , channel thickness; I_D , drain current; V_G , gate voltage; V_D , drain voltage; x , distance. Part **a** is adapted from REF. 177, Macmillan Publishers Limited.

in a hole current once a drain voltage is applied. These holes are compensated by the sulfonate anions of PSS, which in terms of solid-state physics can be considered as ionized acceptors¹³. OECTs based on conducting polymers, such as PEDOT:PSS, work in depletion mode. In the absence of a gate voltage, a hole current flows in the channel (that is, the ON state). Once a positive gate bias is applied, cations from the electrolyte are injected into the channel and the anions are compensated (FIG. 1b). This is equivalent to compensation doping, that is, implanting donors in p-type silicon. As a result, the number of holes in the channel decreases and the film is dedoped as the holes that are extracted at the drain are not replenished at the source. This leads to a drop in the drain current, and the device reaches the OFF state¹¹. By contrast, accumulation-mode OECTs made of semiconducting polymers are normally in the OFF state owing to the small number of mobile holes in the channel (FIG. 1c). Application of a negative gate voltage causes injection of anions into the channel and a corresponding accumulation of holes (electrochemical doping in the language of electrochemistry), leading to the ON state¹⁴.

The identifying characteristic of OECTs is that doping changes occur over the entire volume of the channel, as opposed to a thin interfacial region like in field-effect transistors (FETs) (BOX 1). Therefore, large modulations in the drain current can be achieved for low-gate voltages, which makes OECTs efficient switches and powerful amplifiers^{12,15}. The use of electrolytes instead of MOS capacitors also allows for large flexibility in device architecture and integration with a variety of substrates, employing a variety of form factors and a broad range of fabrication processes. The inherent tunability of organic molecules further enables the optimization of ion and electron transport and facile biofunctionalization. Because of these features, OECTs are being explored for a wealth of applications, including neural interfaces^{16,17}, chemical and biological sensors^{18,19}, printed circuits^{20,21} and neuromorphic devices^{22,23}. In this Review, we discuss the physics of OECTs and the different organic materials used to make the devices, as well as outline the evolution of their technology, highlight various applications and take a critical look at the future of OECT research and development.

The device physics of OECTs

OECTs transduce small voltage signals applied to the gate into large changes in the drain current. This transduction process is described by a transfer curve, which shows the dependence of the drain current on the gate voltage (FIG. 1b,c). The steeper the transfer curve, the larger the change in drain current for a given gate voltage signal. The efficiency of transduction is calculated by the first derivative of the transfer curve, namely, transconductance $g_m = \partial I_D / \partial V_G$, which is an important figure of merit for transistors. OECTs possess very high transconductance values, on the order of millisiemens for micrometre-scale devices¹², which is attributed to the volumetric nature of their response.

An essential consideration in OECT physics is described by the Bernards model¹¹. This model assumes

that ions from the electrolyte enter the channel and change the electronic conductivity throughout its volume, capturing the steady-state and transient response¹¹. According to this model, the device is divided into two circuits: an ionic circuit, which describes the flow of ions in the gate–electrolyte–channel structure, and an electronic circuit, which describes the flow of electronic charge in the source–channel–drain structure according to Ohm's law (FIG. 1d). Therefore, the electronic circuit is treated as a resistor, in which electronic charge drifts under the influence of the local potential in a fashion identical to that of MOSFETs. The ionic circuit consists of a resistor, describing the flow of ions in the electrolyte, in series with a capacitor, describing the storage of ions in the channel. This model implies a purely capacitive process, according to which ions injected in the channel do not exchange charge with the organic film but rather electrostatically compensate the presence of opposite charges²⁴. In this model, therefore, there are no electrochemical reactions between the electrolyte and the channel. At steady state, the capacitor is charged and the gate current goes to zero.

The Bernards model provides a good fit for the output characteristics of OEETs and allows quantitative

predictions of the transconductance, g_m . At saturation and for depletion-mode devices, it gives¹⁷:

$$g_m = (W/L) \cdot d \cdot \mu \cdot C^* \cdot (V_{th} - V_G), \quad (1)$$

where W , L and d are the channel width, length and thickness, respectively; μ is the charge-carrier mobility; C^* is the capacitance per unit volume of the channel; and V_{th} is the threshold voltage. The voltage terms are reversed for accumulation-mode devices. This equation is similar to the one for FETs, with the difference that the product $d \cdot C^*$ replaces the capacitance per unit area of the MOS capacitor, C' . This variation defines the difference between the two devices. In a FET, the physical thickness of the channel does not enter the equation, whereas in an OEET, the channel thickness is a parameter that can tune the performance. For example, in a typical OFET with a 100 nm-thick SiO_2 layer, C' is in the tens of nF cm^{-2} (REF. 25). In OFETs gated with an electrolyte, the C' of the electrical double layer is of the order of $1\text{--}10 \mu\text{F cm}^{-2}$ (REFS 26,27). In an OEET with a 130 nm-thick PEDOT:PSS channel, the product of $d \cdot C^*$, which is the equivalent capacitance per unit area, is $500 \mu\text{F cm}^{-2}$ (REF. 17) (BOX 1). Therefore, volumetric gating gives OEETs a better performance in terms of amplification compared with other transistor technologies¹².

The high transconductance of OEETs comes at the cost of rather slow operation. The Bernards model predicts that the response time is limited by either the ionic or the electronic circuit¹¹. In most devices, the ionic circuit dominates the response time, dictated by the product of the resistance of the electrolyte and the capacitance of the channel. The latter is proportional to the thickness of the channel; therefore, OEETs are slower as d increases. As a result, channel thickness can be used as a parameter to adjust the trade off between gain and bandwidth¹⁷. In practice, microfabricated OEETs with liquid electrolytes can achieve response times of a few tens of microseconds¹², limiting the scope to applications that require maximum frequencies in the range of tens of kilohertz. This is adequate for most biosensor applications, which are quasi-static, and for recording electrophysiological signals²⁸. The use of gel or solid electrolytes leads to even slower response times, yet there are possibilities for application in areas such as printed electronics that do not require fast transistors²⁹.

The Bernards model offers a good starting point for understanding the basic physics of OEETs, but there are other considerations that have been or still need to be taken into account. For example, spatially resolved voltage measurements along the OEET channel imply that the conductivity along the channel varies with charge density in a nonlinear fashion³⁰. Introducing a charge density-dependent conductivity in the Bernards model improves the quality of the output curve fitting of PEDOT:PSS OEETs³¹. Nonideal contacts in OEETs introduce additional complications³². A more accurate description of the transfer curve is achieved by considering the influence of disorder on hole transport in the channel³³. Finally, OEETs represent the limit at which ions freely penetrate the volume of the channel. This has been demonstrated in several materials in which capacitance

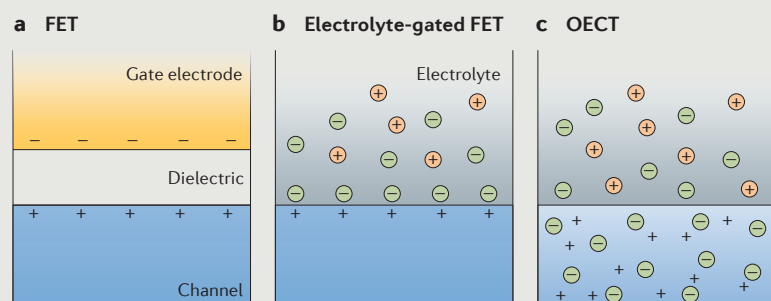
Box 1 | Organic-based transistors

Field-effect transistors (FETs)

In a FET, an organic semiconductor film (the channel) is separated from a metal electrode (the gate) by a thin insulating layer (the gate dielectric). A voltage applied between the gate and the channel leads to field-effect doping of the semiconductor, that is, the accumulation of mobile electronic charge near the interface with the dielectric (figure, part a). The charge in the channel is compensated for by a sheet of charge at the gate electrode. The two sheets of charge form the two plates of a parallel plate capacitor. The amount of charge that is induced in the channel can be estimated by $Q = C \cdot V$, where C is the capacitance of the dielectric and V is the gate voltage. The capacitance is inversely proportional to the distance between the two plates. Therefore, thin dielectric layers maximize the amount of induced charge and thus the drain current of the transistor. In an electrolyte-gated FET, a double-layer capacitor is formed at the electrolyte–channel interface (figure, part b). A sheet of ionic charge in the electrolyte compensates the induced sheet of electronic charge in the channel. This configuration can be considered an extreme case of FET, because the thickness of the dielectric is reduced to dimensions on a par with the ionic radius, resulting in high capacitance.

Organic electrochemical transistors (OEETs)

In an accumulation-type OEET, ions penetrate the semiconductor, leading to changes in the doping state throughout the channel (figure, part c). This configuration is described not by a parallel plate capacitance but by a volumetric capacitance, which can be many orders of magnitude larger. Compared with a FET of similar size, the same gate voltage induces more electronic charge in the channel and thus a larger drain current in an OEET. Similarly, high drain current can be achieved with depletion-type devices.



is found to be proportional to film thickness^{14,17,34}. Electrolyte-gated FETs represent the other limit at which ions accumulate at the surface of the channel. Some materials show behaviour between the two limits^{35,36}, suggesting the presence of a barrier for ion injection. These observations point to an important fundamental issue. The physics of hole and electron injection and transport in organic semiconductors has been extensively studied over the past few decades, whereas little is known about the processes of ion injection and transport in organic semiconductors.

As a consequence of the gating through an electrolyte, OECTs have some specific characteristics. For example, the fraction of the applied gate voltage that drops across the channel is controlled by the nature and geometry of the gate electrode^{37,38}. If a polarizable electrode, such as Pt or Au, is used as the gate, two capacitors are formed in the ionic circuit; one capacitor corresponds to the electrical double layer formed at the gate–electrolyte interface and the other corresponds to the volumetric capacitance of the channel. Because the capacitors are in series, the applied gate voltage drops across the smaller capacitor (FIG. 1d). For efficient gating, the capacitance of the gate electrode must be more than ten times larger than the capacitance of the channel, otherwise a large fraction of the applied gate voltage will drop at the gate–electrolyte interface (FIG. 1d). Such large gates can be technically difficult to implement for some applications; however, using a thick PEDOT:PSS electrode as the gate can help achieve a large gate capacitance. Alternatively, a nonpolarizable gate electrode, such as Ag/AgCl, can be used. In this case, the voltage drop at the gate–electrolyte interface is negligible³⁹, and effective gating is achieved. However, it should be noted that in some sensing applications, a small gate electrode is preferable, for example, when a sensing reaction is meant to occur at the gate and the channel merely acts as the transducer⁴⁰. Finally, the nature of the electrolyte, liquid, gel or solid and the ion concentration influence the response time of the transistor because the electrolyte conductivity determines the resistor of the ionic circuit⁴¹.

Materials for OECTs

The channel of OECTs is typically made of a conducting polymer, most commonly PEDOT or polypyrrole (PPy), doped with p-type dopants such as small anions or polyanions (FIG. 2a,b). These materials are synthesized by solution, vapour-phase or electrochemical polymerization. By far, the most popular material is PEDOT:PSS, which has been explored for a great variety of applications over the past 15 years, owing mainly to its commercial availability in the form of aqueous dispersions, which permits the facile deposition of thin films using solution-processing techniques¹³. The dispersions are prepared by polymerizing EDOT, the monomer of PEDOT, in the presence of PSS. Films of PEDOT:PSS cast from these dispersions show high electronic¹³ (hole) conductivity and are widely used in electrostatic coatings and as anodes for light-emitting diodes and solar cells¹³. As a consequence, the structure and electronic conductivity of these films have been thoroughly

investigated^{42,43}. Various co-solvents, surfactants and processing methods have been used to maximize hole conductivity, which is currently in excess of $1,000 \text{ S cm}^{-1}$ (REF. 44). Electrochemical moving-front measurements revealed that small ions are injected from an electrolyte into PEDOT:PSS films in a barrierless fashion and have drift mobilities close to those in bulk water^{45–47}. Finally, PEDOT:PSS films show good electrochemical stability in aqueous electrolytes⁴⁸ and can be rendered insoluble in water through the addition of crosslinkers such as (3-glycidyloxypropyl)trimethoxysilane^{49,50} and divinylsulfone⁵¹. Overall, it is technically rather simple to make PEDOT:PSS OECTs with a transconductance in the range of millisiemens and a response time in the range of tens of microseconds¹², which makes devices based on this conducting polymer suitable for the vast majority of the applications pursued for OECTs.

Despite the attractive properties and good performance of PEDOT:PSS in OECTs, these films have some limitations. More specifically, the structure of PEDOT:PSS is complex, which limits its use as a model system for structure–function relationships. Also, in terms of electrical properties, the bulky structure of PSS affects the volume fraction of PEDOT in the film and hence the volumetric capacitance²⁴. For this reason, conjugated polymer motifs with higher hole mobility than PEDOT, such as ones that rely on fused thiophenes, have been developed⁵². In terms of mechanical properties, Young's modulus of PEDOT:PSS is considerably higher than that of most biological tissues^{49,53}, which can be a limitation for applications in bioelectronics. Moreover, although PEDOT:PSS films are broadly cytocompatible⁵⁴, polymers or composites allowing more versatile biofunctionalization are desirable. Finally, in terms of solution processing, the acidity of PSS can cause corrosion of the print heads. These limitations motivate researchers to synthesize new materials for OECTs.

Replacing PSS with less acidic polyanions, such as polymers containing (trifluoromethylsulfonyle)imide side groups, results in OECTs with a similar performance in terms of transconductance and response time as PEDOT:PSS-based OECTs⁵⁵. A different approach involves removing PSS and instead attaching ionic groups directly on the thiophene backbone through side chains. Such conjugated polyelectrolytes are semiconducting when the ion is compensated by a counter ion (FIG. 2c) or conducting when compensated by an electronic charge on the conjugated backbone (FIG. 2d). For example, accumulation-mode OECTs with a transconductance of the order of millisiemens have been developed using a semiconductor based on a polythiophene with a sulfonate group attached to the backbone with a hexyl chain (PTHS)⁵⁶ (FIG. 2c). Depletion-mode OECTs have been designed using a conductor based on PEDOT with a pendant sulfonate group (PEDOT-S)⁵⁷ (FIG. 2d). Blending a semiconducting and a conducting conjugated polyelectrolyte yields OECTs that can be tuned by balancing the stoichiometry of the channel⁵⁷. Alternatively, conjugated polymers with hydrophilic or ion-transporting side chains can be used as OECT materials. OECTs made from poly(2-(3,3'-bis(2-(2-(2-methoxyethoxy))

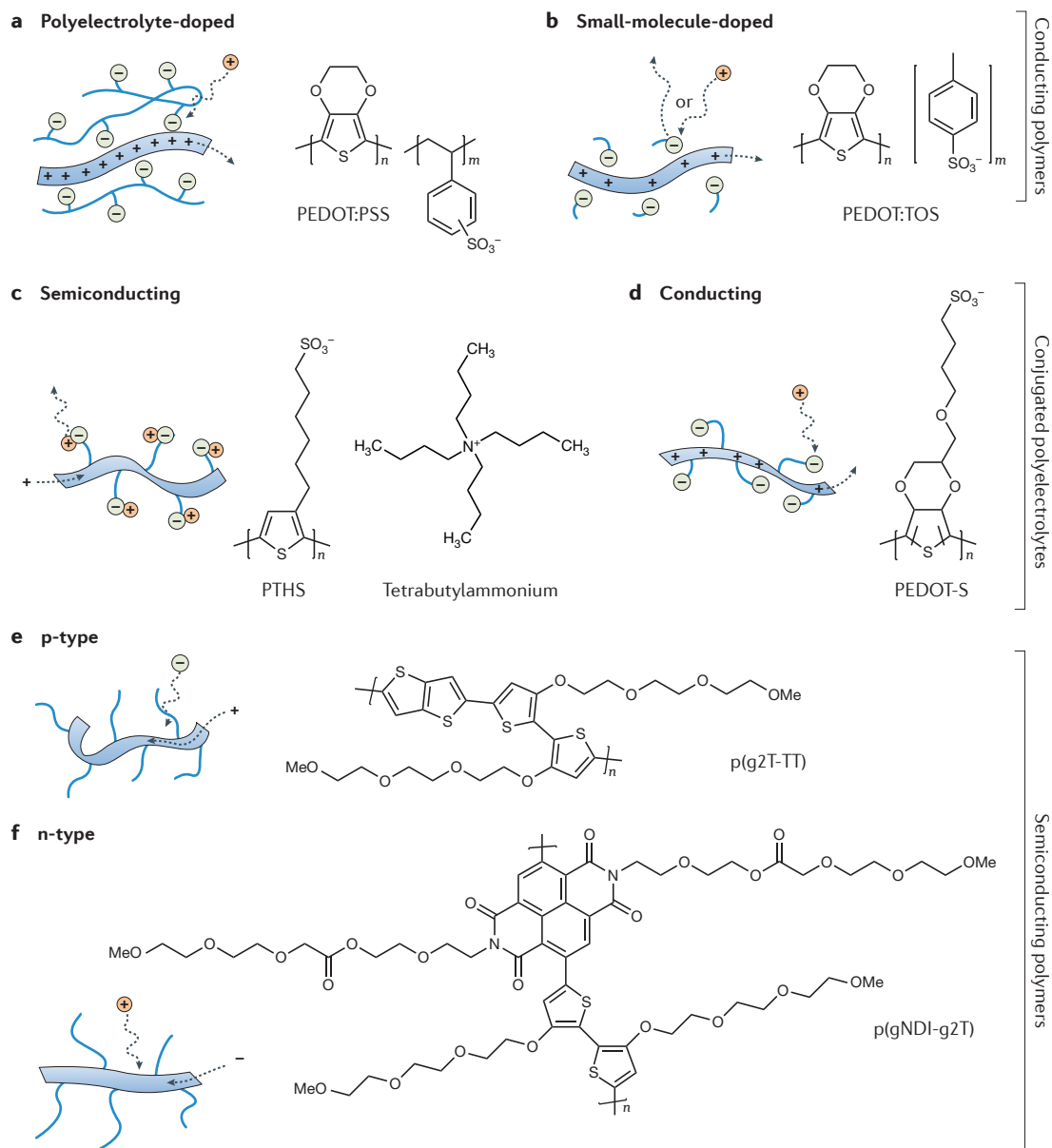


Figure 2 | Different classes of materials used in organic electrochemical transistor channels. Conducting polymers include poly(3,4-ethylenedioxythiophene) doped with poly(styrene sulfonate) (PEDOT:PSS) (part **a**) and poly(3,4-ethylenedioxythiophene) doped with tosylate (PEDOT:TOS) (part **b**). In these materials, holes (represented by plus signs) on the PEDOT backbone are compensated by anions (green circles). Doping takes place through the injection of cations (orange circles) or extraction of anions, accompanied by extraction of holes, as indicated by the arrows. Conjugated polyelectrolytes include semiconducting poly(6-(thiophene-3-yl)hexane-1-sulfonate) tetrabutylammonium (PTHS) (part **c**) and conducting poly(4-(2,3-dihydrothieno[3,4-b][1,4]dioxin-2-yl-methoxy)-1-butanedisulfonic acid) (PEDOT-S) (part **d**). Doping and dedoping mechanisms are indicated by arrows. Semiconducting polymers include p-type poly(2-(3,3'-bis(2-(2-(2-methoxyethoxy)ethoxy)ethoxy)-[2,2'-bithiophen]-5-yl)thieno[3,2-b]thiophene) (p(g2T-TT)) (part **e**) and n-type poly((ethoxy)ethyl 2-(2-(2-methoxyethoxy)ethoxy)acetate)-naphthalene-1,4,5,8-tetracarboxylic-diimide-co-3,3'-bis(2-(2-(2-methoxyethoxy)ethoxy)ethoxy)-(bithiophene)) (p(gNDI-g2T)) (part **f**). These polymers can be doped by the injection of ions, as indicated by the arrows.

ethoxy)ethoxy)-[2,2'-bithiophen]-5-yl)thieno[3,2-b]thiophene) p(g2T-TT), a polythiophene with glycolated side chains, exhibit better transconductance values than PEDOT:PSS-based OECTs of the same geometry³⁶ (FIG. 2e). Using the same side-chain functionalization, an n-type copolymer poly((ethoxy)ethyl 2-(2-(2-methoxyethoxy)

ethoxy)acetate)-naphthalene-1,4,5,8-tetracarboxylic-diimide-co-3,3'-bis(2-(2-(2-methoxyethoxy)ethoxy)ethoxy)-(bithiophene)) p(gNDI-g2T), based on naphthalene-1,4,5,8-tetracarboxylic diimide and bithiophene units, was used to design ambipolar OECTs with high stability during pulsed measurements over 2 hours in aqueous media³⁴ (FIG. 2f). Finally, the blending of

PEDOT:PSS with poly(vinyl alcohol) (PVA) provides a handle for subsequent silanization, allowing for the covalent linkage of biological moieties onto the films without any deleterious effects on the electrical properties⁵⁸. It has been demonstrated that these films can be functionalized with polypeptides and proteins that maintain their biological activity.

Electrochemical polymerization is a versatile method for incorporating biomolecules in conducting polymers⁵⁹ and was used to fabricate the first OECT¹⁰. However, the method has fallen out of favour because it relies on growth from a conducting surface, which is hard to implement in OECTs. An alternative method, vapour-phase polymerization, can also incorporate different biomolecules in the channel of OECTs. In this process, a film cast from a precursor solution containing tosylate (TOS, the pendant group of PSS) moieties is exposed to EDOT vapour to yield the conducting polymer PEDOT:TOS⁶⁰ (FIG. 2b). The mixing of different polymers in the precursor solution results in high-quality composites. Indeed, composites of PEDOT:TOS with polyethylene glycol (PEG) have OECT performance similar to that of pristine PEDOT:TOS⁶¹. The use of a carboxyl-containing PEG demonstrates the potential of vapour-phase polymerization in applications requiring biofunctionalization. Furthermore, gelatin, which is the denatured form of the extracellular matrix protein collagen, can be incorporated into PEDOT:TOS without altering the electrochemical properties of the conducting polymer or its performance in OECTs⁶². Such composites were found to support bovine brain capillary endothelial cell adhesion and growth *in vitro*, indicating a functional protein. Finally, vapour-phase polymerization can be applied to produce PEDOT:TOS composites with poly(tetrahydrofuran), which show a hysteresis effect in their OECT characteristics⁶³. The hysteresis is attributed to a conformational change in the polymer during redox cycling and was used to demonstrate a nonvolatile memory device.

A variety of electrolytes, including gels⁶⁴ and solids⁶⁵, and the use of different gate electrodes, including traditional polarizable electrodes (such as Pt)⁶⁶ and non-polarizable electrodes (such as Ag/AgCl⁶⁶) as well as non-traditional materials (such as PEDOT:PSS⁶⁵ and various forms of carbon^{67,68}), have been used to fabricate OECTs. The choice of material is often dictated by the application or limitations imposed by fabrication. To test new channel materials, the components commonly used are prepatterned Au source and drain electrodes on a glass substrate, a Ag/AgCl gate electrode and an aqueous solution of NaCl or KCl as the electrolyte.

The history of OECT technology

In 1980, the first indirect measurements of the reversible electrochemical switching of electronic conductivity in polypyrrole, recorded from films made on Pt electrodes, were reported⁶⁹. A few years later, polypyrrole films electropolymerized onto Au, separated by 1.4 μm gaps on SiO₂-coated Si wafers, were shown to extend and even bridge the gaps between electrodes¹⁰. This device had the action of an accumulation-mode transistor, which was recorded using a two circuit drain-source and a

gate-counter-reference electrode probing approach. Since then, different probing setups and other polymers, such as polypyrrole, poly(3-methylthiophene)⁷⁰ and polyaniline⁷¹, have been applied as the active layer in electrochemical transistors for redox sensing and chemiresistor applications⁷². In addition, several OECTs based on microfabricated lateral electrodes on rigid substrates have been reported (FIG. 3a). Specifically, advances have included the fabrication of sandwich structures⁷³, the incorporation of solid electrolytes^{74,75}, the use of channels that incorporate diaphorase enzymes⁷⁶ and the demonstration of high performance in aqueous and nonaqueous electrolytes⁷⁷.

The use of electrolytes as gating media allows for great flexibility in OECT design in terms of placement of the gate electrode with respect to the channel. Moreover, 'long-channel' effects can be addressed. In OFETs, charges are transported along the thin sheet of accumulated holes or electrons, residing at the semiconductor-gate dielectric interface. In a long channel, this typically results in very low currents, preventing the use of OFETs as drivers for power consuming components. This is particularly problematic in all-printed systems, where only long channels can be manufactured with high yield. By contrast, in OECTs, the entire bulk contributes to charge transport; thus, higher currents can be supplied for the same given channel length. Therefore, different designs of OECTs with low operating voltage can be fabricated with respect to gate, electrolyte, channel dimensions and relative positions. Additionally, different deposition and patterning techniques on a variety of substrates, including flexible and stretchable substrates, can be applied, paving the way for drastically new device architectures and form factors (FIG. 3b).

The first electrochemical transistor that was, in part, manufactured using printing techniques was reported in 1994 (REF. 78). Carbon-based source and drain electrodes and dielectrics were screen-printed on a polyvinyl chloride base, and the assembled structure was then cracked in liquid nitrogen. Polyaniline was anodically grown along the fractured edge and coated with glucose oxidase (GOx) immobilized in poly(1,2-diaminobenzene). The resulting device, with a channel length and width of 20 μm and 4.5 mm, respectively, was used as a micro-electrochemical enzyme transistor for glucose⁷⁹ and peroxide sensing⁸⁰. An OECT with a channel length of 0.5 mm gated through a thick filter paper soaked with 1 M KCl electrolyte was also reported⁸¹.

In the early 1990s, PEDOT was explored as an electronic ink and coating for a wide range of conductive, electronic and electrochemical applications⁸²⁻⁸⁴. When combined with the dopant PSS, PEDOT shows good redox stability and high electronic conductivity, and can be incorporated into high-performing OECT structures. Using printing techniques, devices in which PEDOT:PSS serves as both the active channel and the electrode for the gate, drain and source are possible. A decade later, the *in situ* redox switching of the electronic conductivity in PEDOT was explored using different electrochemical setups and device configurations, such as electrochromic pixels^{85,86}. In 2002, the first demonstrations of transistors

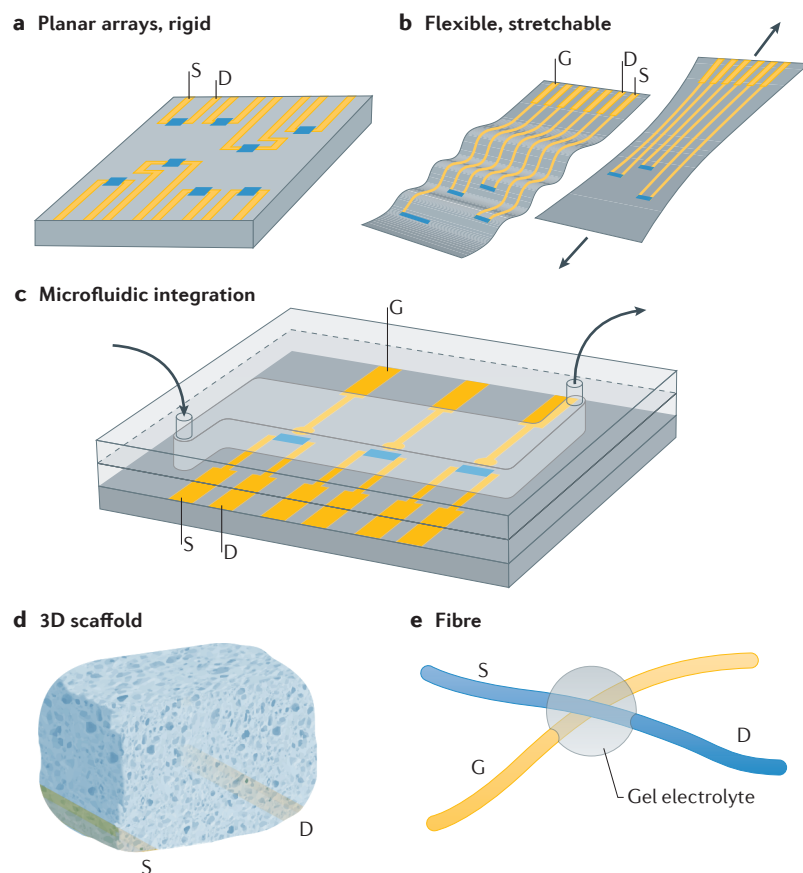


Figure 3 | Form factors of organic electrochemical transistors. Organic electrochemical transistors (OECTs) are available in a variety of form factors, including planar devices on rigid substrates (part **a**), devices that are flexible and stretchable (part **b**), devices that are integrated with microfluidics (part **c**), devices with channels in the form of 3D scaffolds (part **d**) and devices made of fibres (part **e**). D, drain; G, gate; S, source.

with PEDOT were reported^{65,87,88}. For example, by deactivating or patterning PEDOT:PSS coatings using screen printing, an all-laterally configured gate, drain and source OECT with a screen-printed gelled electrolyte on top could be realized⁸⁷. In such lateral OECTs, drain current ON/OFF ratios of 10^5 , a transconductance of 1.2 mS and a maximum frequency operation of 200 Hz can be achieved.

Easy manufacturing protocols for high-performing and low operating-voltage OECTs sparked the development of various OECT structures that are based on PEDOT:PSS and other mixed ionic–electronic polymer conductors as well as the development of related high-volume manufacturing processes. Lateral PEDOT:PSS-based OECTs can be combined with vertical electrochromic display cells and manufactured by printing techniques on coated paper to form actively addressed smart pixels and displays⁸⁹. Long PEDOT:PSS channels enable integration and gating through microfluidic systems made from polydimethylsiloxane (PDMS)⁹⁰ (FIG. 3c), a technology that also facilitates OECT gating through a phospholipid membrane⁹¹ and through cells⁹². Polyaniline, PPy and PEDOT nanowires can be grown between Pt source and drain electrodes

and remotely gated through an electrolyte⁹³. OECTs were also developed using 3D porous sponges of PEDOT:PSS, a form factor of interest for tissue culture applications⁹⁴ (FIG. 3d).

Paper and plastic foils are among the largest surfaces ever manufactured and therefore have attracted great attention from the OECT community. Several approaches to standard and modified printing techniques have been explored to produce OECT devices and circuits along those surfaces, such as screen printing⁹⁵ and inkjet printing⁹⁶. All-screen-printed OECT logic circuits, such as flip flops and shift registers operating at 1.5 V, have been achieved on poly(ethylene terephthalate) (PET) substrates²¹. An ultrathin carrier, made on a 4 µm-thin parylene sheet, for OECTs has been explored in bioelectronic applications¹⁶. Textiles are also an attractive carrier for OECTs, with potential applications in the field of wearable electronics. For example, PEDOT-based transistors have been made on Gore-Tex as gas sensors on ‘breathable’ substrates⁹⁷ and have also been screen-printed on common fabrics, such as woven cotton and Lycra, to serve as wearable sensors for the sensing of external biological fluids, for example, sweat, saliva and urine⁹⁸.

Paper and textiles are made of fibres, and several approaches have been explored to build OECTs and even complex circuits on individual or combinations of fibres⁹⁹ (FIG. 3e). For example, OECTs based on PPy made on a nylon nanofibre can be explored for lead-ion detection¹⁰⁰, and PEDOT:PSS soaked into natural cotton fibres can be used to form an OECT channel for saline sensing¹⁰¹. PEDOT:PSS has also been explored in combination with nanofibrillated cellulose (NFC) as a cladding layer around the fibres. This combination provides a scalable technology for self standing and large-scale OECT systems, for instance, a reconfigurable OECT sticker platform¹⁰². A transconductance beyond 1 S has also been demonstrated in PEDOT:PSS–NFC OECTs¹⁰³. Finally, a unique form factor has been achieved by making OECTs from PEDOT derivatives that are infused into living plants¹⁰⁴. Such OECTs are envisioned to monitor and control plant development in the future.

Applications of OECTs

Bioelectronics

Organic electronic materials and OECTs have a major role in various bioelectronic devices for health care-related uses and biomedical research^{54,105,106}. In electrophysiology, OECTs are interfaced with electrically active tissues and organs to measure cell activity (FIG. 4a). For example, microfabricated PEDOT:PSS OECTs on parylene substrates can be placed on the brain of a rat to record epileptic seizures. The signal-to-noise ratio of such recordings is over 20 dB higher than that of PEDOT:PSS electrodes¹⁶, and, owing to local signal amplification, activities from deep brain tissue can be recorded. As a consequence of the direct and oxide-free contact between the conducting channel and cerebrospinal fluid, OECTs can also be used to locally inject current and stimulate neurons¹⁰⁷. OECTs that are integrated with organic thin-film transistors are capable of

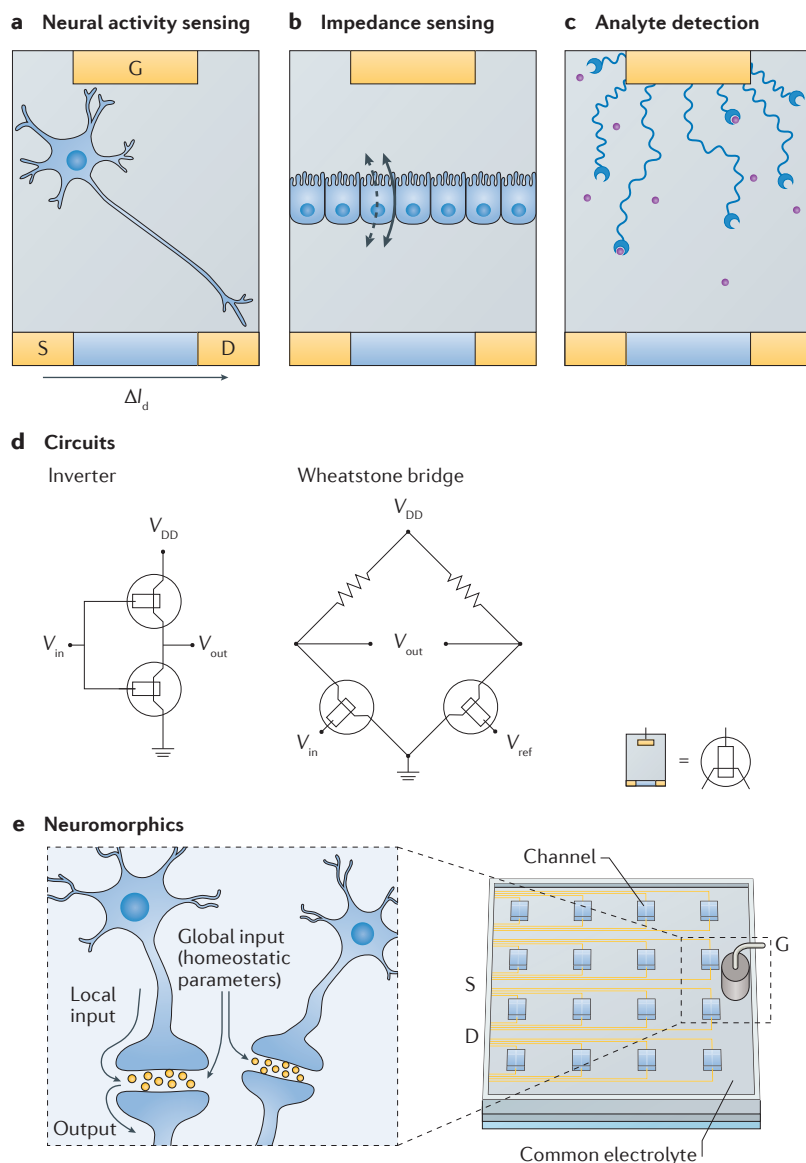


Figure 4 | Applications of organic electrochemical transistors. Organic electrochemical transistors (OECTs) are used in electrophysiology to record the electrical activity of cells, such as neurons, in the electrolyte between the channel and the gate (part **a**). They are also used as impedance sensors that record changes in ion permeability of cell layers placed between the channel and gate (part **b**) and for the detection of analytes (red circles) that interact with receptors placed at the gate or channel (part **c**). In all these cases, the detection of an event is signalled by a change in the drain current, ΔI_d . A variety of circuits, including inverters and Wheatstone bridges (part **d**), have been developed to process an input voltage signal V_{in} to an output voltage signal V_{out} . OECTs can also be used as devices that mimic features of biological neural networks, such as the ability to control an entire network through a global signal (part **e**). D, drain; G, gate; S, source; V_{DD} , supply voltage; V_{ref} , reference voltage.

recording myograms in transgenic rats with high temporal resolution¹⁰⁸. Cutaneous applications are also being explored. For example, OECTs can record an electrocardiogram when placed on human skin¹⁰⁹. OECTs can further amplify recordings of electrophysiological signals from the human brain, heart and muscle^{17,110,111}. Finally, PEDOT:PSS OECTs can be sterilized by autoclaving, paving the way for clinical applications¹¹².

OECTs can also be used in conjunction with cell cultures for drug screening. For example, OECT arrays can record action potentials from cardiomyocytes with excellent signal-to-noise ratio¹¹³ and provide a spatial map of the electrophysiological activity¹¹⁴. OECTs can also be used to monitor cell coverage¹¹⁵, barrier tissue formation and cellular health^{116–120} for nonelectrogenic cells, such as epithelial cells (FIG. 4b). Most of these measurements involve the growth of a monolayer of cells between the channel and the gate, which introduces a barrier for ion motion in the electrolyte and therefore alters the characteristics of the OECT¹²¹. The same principle can be applied to study ion channels in supported lipid bilayers assembled on PEDOT:PSS channels¹²². Measurement protocols have been developed, using AC modulations¹²³ or white noise¹²⁴ applied at the gate, in which OECTs show superior performance compared to impedance sensing using electrodes. Given the optical transparency of PEDOT:PSS in the visible part of the spectrum, a key advantage of OECT devices is the possibility of simultaneous optical and electronic readouts¹²⁵. Another advantage is that they work in complex environments, such as milk, where they were used for the detection of enteric pathogens by measuring trans-epithelial ion flow¹²⁶. OECTs have also been applied to 3D cell culture models; for example, OECTs can be integrated with cyst-like 3D cultures to monitor their integrity and the effect of toxic compounds on the cell structure¹²⁷. Finally, it should be mentioned that the arrangement of epithelial cells on an OECT channel can be controlled by the applied drain and gate voltage¹²⁸. This offers the opportunity to not only monitor but also control cell behaviour. To this end, OECTs fabricated using porous sponges of PEDOT:PSS were able to host and control 3D cell cultures⁹⁴.

OECTs can also act as transducers in biosensors for the detection of electrolytes and metabolites, such as glucose and lactate, which are important for human health and performance monitoring (FIG. 4c). A variety of approaches have been developed to gain selectivity in ion detection^{129,130}. For the detection of metabolites, the principle of sensor operation relies on the selective interaction of a redox enzyme with the metabolite and the consequent transfer of an electron to the gate of the OECT. The resulting change in the drain current depends on the concentration of the metabolite⁴⁰. Initially, the enzyme is entrapped in the channel⁷⁹ or dissolved in the electrolyte¹³¹. Immobilization of the enzyme on the gate electrode then leads to the development of highly selective and sensitive sensors^{132,133}. The combination of OECTs with microfluidics paves the way for multi-analyte sensor platforms^{134,135}, whereas combination with textiles allows for their use in wearable applications, for example, for the detection of analytes in sweat^{98,136}.

Although many applications of OECTs have focused on analyte detection in saline solutions, examples of sensing in breath¹³⁷, sweat¹³⁸, saliva¹³⁹ or cell culture media¹⁴⁰ have also been demonstrated. These demonstrations make OECTs clinically relevant, as exemplified by the use of OECT lactate sensors to measure

the metastatic potential of tumour cells¹⁴⁰. Moreover, OECTs provide an easy way to amplify fast-scan cyclic voltammetry, allowing for simpler instrumentation compared to commercially available tools¹⁴¹. For example, OECTs enable the selective detection of dopamine in the presence of interfering compounds, with sensitivities and limits of detection comparable to, or better than, those obtained using sophisticated electrochemistry techniques such as differential pulse voltammetry¹⁴². Similarly, the highly sensitive detection of adrenaline with OECTs has been reported¹⁴³. Finally, in separate studies, OECTs have been shown to be suitable for the sensing of DNA¹⁴⁴ and bacteria¹⁴⁵.

Circuits and logic

The high transconductance and ON/OFF ratios along with low-voltage operation have encouraged scientists to incorporate OECTs in circuits (FIG. 4d). However, the relatively low switching speed compared to MOSFET technology prevents their application in (digital) signal processing and computation. Nevertheless, combining OECTs with silicon-based integrated circuits offers many promising opportunities, for example, providing internet connectivity in electronic label and skin-patch applications¹⁴⁶. The first step in demonstrating operational OECT circuits was taken in 2002, when OECTs were included as pixel drivers in an active-matrix electrochromic display printed on paper⁸⁹. PEDOT:PSS OECT circuits have also been explored to improve the matrix display fill factor¹⁴⁷ and to achieve negative-AND (NAND) and NOR gates²⁰. Textiles and wire configurations, in addition to paper and plastic foils, represent an important large area and flexible platform for OECTs, where the fibre grid can potentially serve as a template or as an integral part of devices to connect and define circuits. Woven OECT logic circuits⁹⁹, NOR gates and inverters, using parallel PEDOT:PSS-based fabric wires combined with a polyelectrolyte, have already been achieved¹⁴⁸. Similar to display pixels, sensor and detector devices can be arranged in matrices to enable spatially resolved sensing or detection. In such devices, OECTs can serve as the addressing switch or line and row driver to facilitate the *x-y* addressing of individual sensors in a crosspoint matrix. In an effort to achieve a touchless control interface, OECTs were printed and integrated to form addressing columns and readout rows for a ferroelectric sensor matrix¹⁴⁹.

Analogue and logic OECT circuits have been realized for a variety of applications using different large-area and high-volume manufacturing techniques, such as screen printing^{21,150}, lamination¹⁴⁷, nanoimprinting¹⁵¹, combined inkjet printing and vapour-phase polymerization¹⁵². A tenfold increase in sensitivity can be achieved using a PEDOT:PSS-based signal-ON sensor circuit, compared with a single OECT sensor¹⁵³. Such sensor circuits can be applied for metabolite detection; for example, a Wheatstone bridge consisting of two PEDOT:PSS-based OECTs can be used for lactate sensing¹⁴⁰. A voltage amplifier, combining a high-transconductance OECT with a resistor, enables improved recordings of electrocardiographic signals compared with electrodes¹¹¹.

Supercapacitor and energy-storage technology constitute other potential areas for the use of electrolyte-based devices. In energy-storage modules, several capacitors are typically included, with the need for high-transconductance switches to balance charging and discharging. An OECT-based differential amplifier was manufactured to balance and limit the voltage across capacitors to 1 V (REF. 150).

Memory and neuromorphic devices

There is great interest in developing device networks involving the co-location of computation and memory because of their efficiency in learning specific tasks, such as pattern recognition^{154–156}. These systems are termed neuromorphic because they mimic the structure and function of the nervous system. Neuromorphic systems rely on devices that display temporary or permanent changes in electrical properties, thereby simulating short-term or long-term memory. Ions in OECTs can change the electrical state of the channel; therefore, a variety of memory and neuromorphic devices have been developed based on OECTs (FIG. 4e). For example, in an adaptive device based on a polyaniline channel and an electrolyte based on LiCl in poly(ethylene oxide)¹⁵⁷, hysteresis during a voltage sweep gives rise to bistable operation, which imparts a dependence of the channel resistance on the history of the device. Programmed states are stable for timescales of ~1,000 s (REF. 158). Follow-up work explored the integration of these devices in neural network architectures¹⁵⁹. Devices using different electrolytes¹⁶⁰ and channel materials^{161,162} were evaluated.

In general, an attractive feature of neuromorphic devices is their potential for low power consumption per switching event. This was demonstrated in devices based on polymer nanofibres that exhibit energies as low as 1.23 fJ per synaptic spike¹⁶³. The first neuromorphic transistor based on a PEDOT:PSS OECT was described in 2015, and neuromorphic functions, such as paired-pulse depression, adaptation and dynamic filtering, were demonstrated²². The retention time can be further increased from a few seconds to several hours by replacing PEDOT:PSS with a modified polymer that undergoes a conformational change upon charging¹⁶⁴. A system using multiple gates to modulate a single channel is able to discriminate the orientation of voltage patterns imposed on the gate electrode array, emulating the orientation selectivity of the mammalian visual system¹⁶⁵. Another system using multiple channels and a single gate imitates homeostatic plasticity functions of the brain¹⁶⁶. A different architecture for an organic neuromorphic device combines a battery^{167,168} and an OECT. This design allows the inclusion of over 500 distinct synaptic states in a narrow (<1 V) voltage range and ensures that the programmed states change by less than 0.1% over tens of hours²³. Finally, a ferroelectric polymer layer, coated on the gate electrode, can be used to control the redox state of a PEDOT:PSS channel¹⁶⁹. Polarization switching of the ferroelectric polymer, which takes place once the coercive field is overcome, introduces a bistability that implements memory functionality.

Outlook

OECT research is at the intersection of materials science, solid-state physics, electrochemistry and electrical engineering. Although the Bernards model describes the physics of OECTs, it still needs refinement to better understand and optimize device operation. For example, the lateral motion of ions inside the channel has to be considered, which requires the development of 2D drift or diffusion models with appropriate boundary conditions at the electrolyte–channel interface. On a more fundamental level, although electronic charge injection at metal–organic interfaces has been well studied^{170,171}, little is known about ion injection from electrolytes into organic semiconductors owing to the difficulty in measuring ion injection and transport in the presence of electronic charge⁴⁵. These processes are expected to be sensitive to the microstructure of the polymer and therefore should be analysed at a microscopic level¹⁷². Moreover, charge transport in OECT channels is complex^{173,174} owing to the presence of water, high charge densities and dopants. For example, the effect of a large amount of water on the density of states of organic semiconductors remains elusive. However, computational methods that could answer this question are within reach. Finally, the development of simulation program with integrated circuit emphasis (SPICE) models is expected to greatly boost the design of OECT-based circuits^{175,176}.

Polymers with better performance than PEDOT:PSS are being developed. However, the lack of structure–function relationships hinders the rational design and synthesis of new materials. The development of *in situ* and *operando* measurements that combine structural, spectroscopic and electrical properties is particularly important because the film structure changes upon immersion and operation in an electrolyte environment^{46,47,172}. Material properties need to be adapted to the purpose, environment and operational lifetime of a given device and application. For example, a stability of several weeks in aqueous electrolyte is a primary consideration for cell culture-based diagnostics, whereas a stability of a few minutes might be adequate for disposable sensors. Biocompatibility is crucial for implantable devices but not for memory-storage devices. Reversibility of the drain current through repeated gate pulses is highly desirable for most circuit and sensing applications, whereas hysteretic behaviour through trapping and retention of ions, and morphology changes in the channel allows for applications in memory and neuromorphic devices. Finally, the possibility to tailor ion selectivity paves the way for the development of different biosensors.

A consideration for materials design that is critical for all applications stems from the fact that the channel of an OECT must perform two tasks: transport electronic charge (measured by μ) and store ionic charge (measured by C^*). According to Equation 1, the figure of merit of the material is defined by the product of the charge-carrier mobility and volumetric capacitance ($\mu \cdot C^*$). For example, PEDOT:PSS with ethylene glycol has a $\mu \cdot C^*$ of $75 \text{ F cm}^{-1} \text{ V}^{-1} \text{ s}^{-1}$ (REF. 17), whereas p-type materials, such as p(g2T-TT) (FIG. 2e), achieve

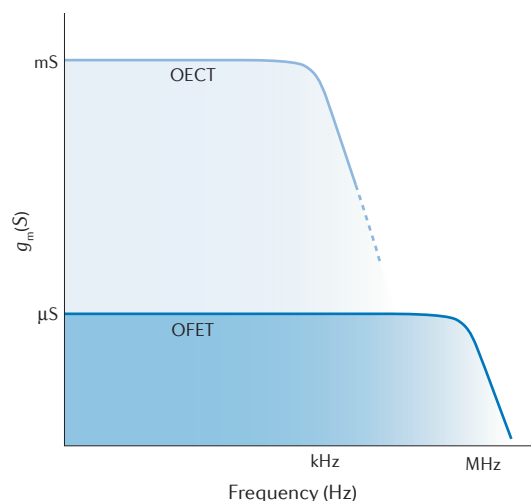


Figure 5 | Comparison between organic electrochemical transistors and organic field-effect transistors. The two devices are compared from the perspective of gain versus bandwidth. Typical organic electrochemical transistors (OECTs) show a transconductance, g_m , in the range of millisiemens, but g_m starts to roll off for frequencies higher than 1 kHz. Organic field-effect transistors (OFETs) show a lower transconductance, but they can be operated at higher frequencies. The area under the pale blue curve indicates the frequency range in which OECTs have a performance advantage.

a $\mu \cdot C^*$ of $228 \text{ F cm}^{-1} \text{ V}^{-1} \text{ s}^{-1}$ (REF. 36). By contrast, n-type materials, such as p(gNDI-g2T) (FIG. 2f), have a $\mu \cdot C^*$ of $\sim 0.1 \text{ F cm}^{-1} \text{ V}^{-1} \text{ s}^{-1}$ (REF. 34). Decoupling the charge-carrier mobility and volumetric capacitance can explain why one material outperforms the other¹⁷⁷. For example, p(g2T-TT) has a higher $\mu \cdot C^*$ than PEDOT:PSS because of a six times higher volumetric capacitance, but has a comparable hole mobility. p(gNDI-g2T) has the highest reported C^* ($\sim 400 \text{ F cm}^{-3}$), but low electron mobility ($\sim 1 \times 10^{-4} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$). A rule emerging from available materials is that even minimal hydrophilicity encourages ion transport and therefore is a requirement for OECT materials^{14,34,36,45,178}. However, hydrophobic self-doped conjugated polyelectrolytes¹⁷⁹ and poly(3-hexylthiophene) have also been used as channel materials in water-based OECTs¹⁷². Additionally, block copolymers or blends of semiconducting and ion-conducting polymers allow for the separate control of ion and electron transport¹⁸⁰, which makes them interesting for OECTs. Finally, small molecules are envisioned to play a key role in the development of OECTs with tunable structure–function relationships.

OECTs have great design flexibility and can be manufactured by a variety of fabrication techniques, leading to different form factors compatible with low-cost, flexible, large-area and wearable applications. Advantages such as high transconductance, stability in aqueous electrolytes, cytocompatibility and facile biofunctionalization make them particularly suitable for bioelectronics. Materials with tailored biological properties, for example, modified with enzymes, can be used for OECT-based biosensors. Although OECT-based biosensors have been

tested only *in vitro* so far, *in vivo* applications are envisioned. OECTs can also be fabricated from materials that are optically transparent, allow electromechanical activation¹⁸¹ and leverage ion transport for drug delivery¹⁸², which makes them suitable as multimodal tools for cell monitoring. Three-dimensional cell culture platforms made of conducting polymers¹⁸³ offer the opportunity to control the mechanical, biochemical and electrical microenvironment of a cell and to simultaneously monitor cell behaviour. The combination of high-performance OECT sensors with high-end silicon electronics through heterogeneous integration will facilitate the development of large multiplexed arrays for electrophysiology¹⁸⁴. By contrast, simple OECT circuits interfaced with sensors for multiplexing, processing and amplification will benefit from the simplicity of an all-organic technology and will be relevant to ‘quasi-static’ applications such as biosensor arrays. Ion gels, such as those used in organic FETs¹⁸⁵, can render OECTs suitable for printed electronic applications. Moreover, the ability of OECTs to conduct large currents makes them interesting for applications in power electronics. Finally, the first devices for neuromorphic computing using OECTs have already been developed. The next step entails the scaling up of the number of devices and the scaling down of the individual device size to demonstrate the potential of OECT-based neuromorphic computing.

Finally, to discuss OECTs in relation to OFETs, the two devices represent the opposite ends of the same spectrum in terms of operation mechanism. They share many properties and are similar in terms of materials, processes and form factors. However, OECTs are

a considerably less mature technology than OFETs. When compared from a gain versus bandwidth perspective (FIG. 5), the transconductance of OECTs is larger than that of OFETs up to a certain frequency, beyond which OFETs have the performance advantage. For a typical microfabricated OECT ($W \times L = 10 \times 10 \mu\text{m}^2$, $d = 100 \text{ nm}$), the transconductance is in the range of mS and starts to roll off at kilohertz frequencies. An OFET of similar size with a hole mobility of $1 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ and with $C' = 1 \mu\text{F cm}^{-2}$ (dielectric made of a self-assembled monolayer) has a transconductance of around $1 \mu\text{S}$, which extends to megahertz frequencies. However, the transconductance of an OECT changes depending on the nature of the electrolyte; for example, a gel or solid electrolyte leads to slower devices. Therefore, the exact frequency at which OECTs lose the performance advantage over OFETs depends on the nature of the electrolyte and therefore on the specific OECT design. Other metrics, such as the ON/OFF ratio, linearity of characteristics, electrical stability and environmental stability, are difficult to compare because they have not been well studied for OECTs. Nevertheless, OECTs have a higher transconductance than OFETs up to a frequency well beyond their roll-off value, suggesting that they can replace OFETs in many applications. However, applications that require the highest possible frequencies, such as in radio frequency identification tags or display driving circuitry, remain difficult areas for the implementation of OECTs. Assuming a similar rate of progress for OECTs as for OFETs, the next few years will bring great progress in OECT technology, which could result in their commercialization.

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